Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO-220 plastic package.

2. Features and benefits

- Trench structure
- High junction temperature up to 150°C
- Low forward conduction voltage
- · Negligible switching losses

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 129 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	-	10	А
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 129 °C; square-wave pulse; both diodes conducting	-	-	20	Α
Static chara	acteristics					
V_{F}	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode	-	0.56	0.62	V
		I _F = 5 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode	-	0.52	0.58	V
		I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode	-	0.7	0.75	V
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode	-	0.63	0.7	V
I _R	reverse current	$V_R = 100 \text{ V}; T_j = 25 \text{ °C}; Fig. 7; Fig. 8;$ per diode	-	-	50	μA
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode	-	-	15	mA

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Dual power Schottky diode

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		A1 A2
2	K	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		
			TO-220E	

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNS20H100C	TO220	WNS20H100CQ	Tube	50	TO220E	26-April-2019

Dual power Schottky diode

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_{RWM}	limiting crest working reverse voltage		-	100	V
V_R	limiting reverse voltage	DC	-	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 129 °C; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3	-	10	А
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 129 °C; square-wave pulse; both diodes conducting	-	20	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	-	180	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	-	198	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

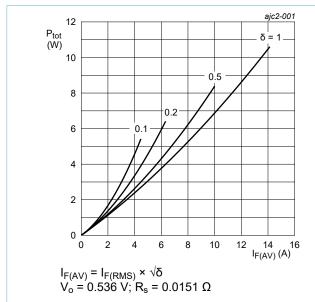


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode

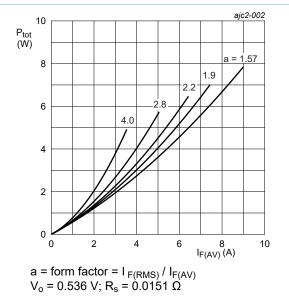


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

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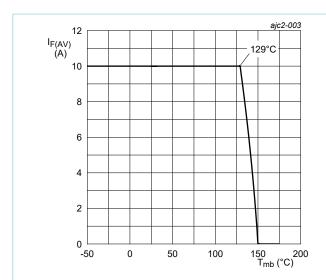


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

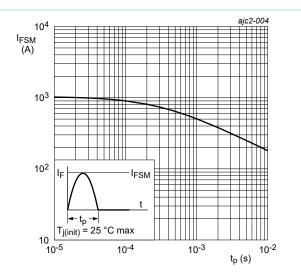


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

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8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	per diode; Fig. 5	-	-	2.5	K/W
		both diodes conducting	-	-	1.2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

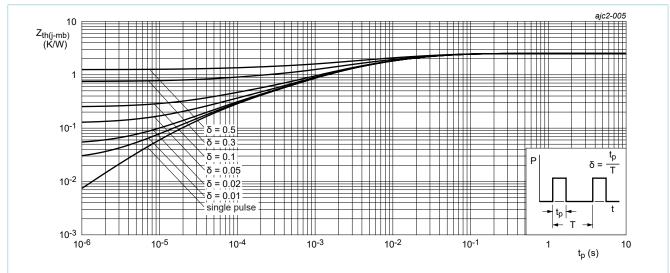


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; per diode

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9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static characte	Static characteristics							
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode		-	0.56	0.62	V	
		I _F = 5 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.52	0.58	V	
		I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode		-	0.7	0.75	V	
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.63	0.7	V	
I _R	reverse current	$V_R = 100 \text{ V}; T_j = 25 \text{ °C}; Fig. 7; Fig. 8;$ per diode		-	-	50	μΑ	
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode		-	-	15	mA	

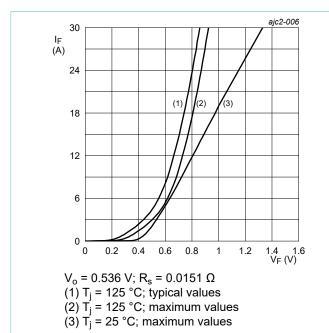
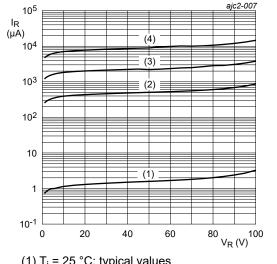


Fig. 6. Forward current as a function of forward voltage, per diode

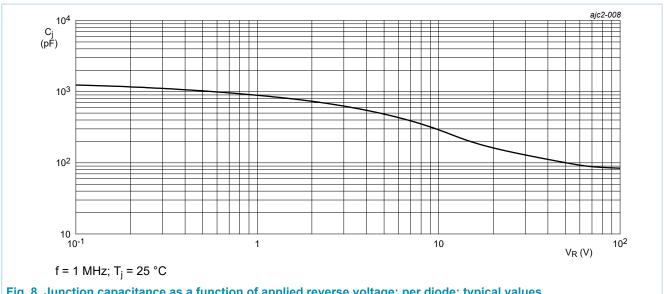


- (1) T_i = 25 °C; typical values
- (2) $T_j = 100 \,^{\circ}\text{C}$; typical values (3) $T_j = 125 \,^{\circ}\text{C}$; typical values
- (4) T_i = 150 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical values

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10. Package outline

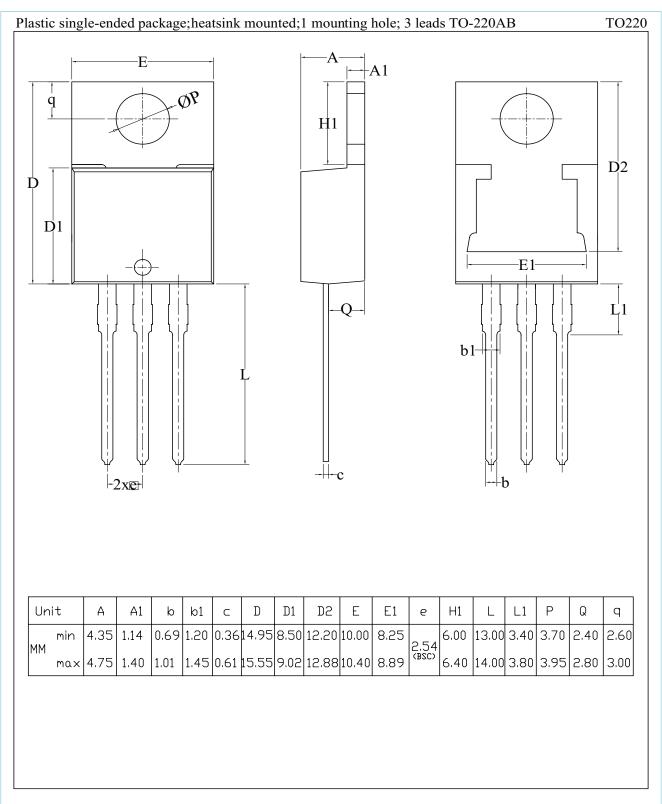


Fig. 9. Package outline TO-220E

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11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 26 April 2019

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